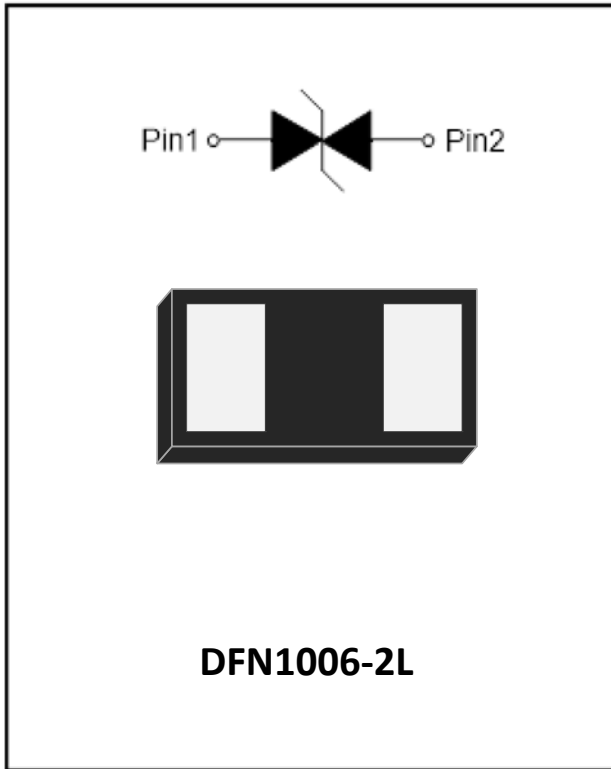


1-Line, Bi-directional, Transient Voltage Suppressor



Features

- Stand-off voltage: 3.3V Max
- Transient protection for each line according to
IEC61000-4-2(ESD): $\pm 30\text{kV}$ (contact)
IEC61000-4-5(surge): 8A (8/20 μs)
- Low leakage current
- Low clamping voltage
- Low clamping voltage:
- RoHS Compliant

Applications

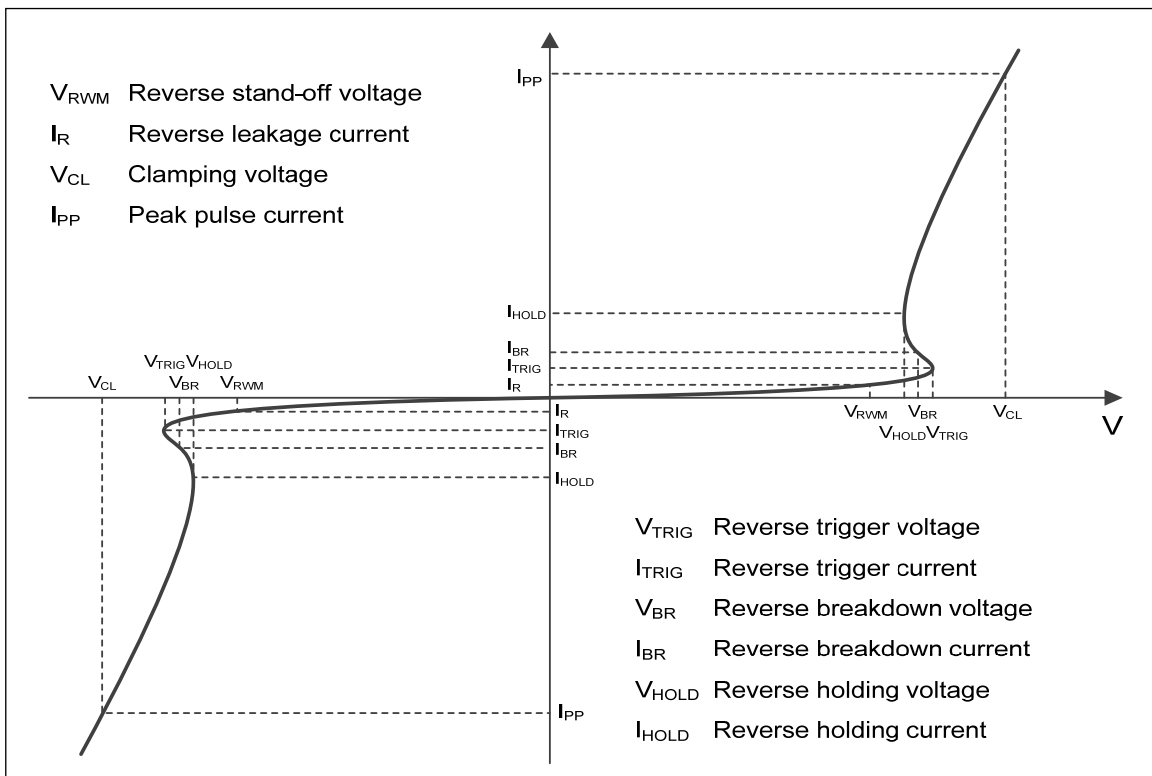
- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- Audio Players
- Keypads, Side Keys, LCD Displays

Mechanical Data

- Package: DFN1006-2L
- Case Material: "Green" Molding Compound
- Moisture Sensitivity: Level 3 per J-STD-020
- Marking Information: See Below

3X

Definitions of electrical characteristics





ESD3V3LBS

■Maximum Ratings

PARAMETER	SYMBOL	LIMITS	UNIT
Peak pulse power ($t_p = 8/20\mu s$)	P_{pk}	80	W
Peak pulse current ($t_p = 8/20\mu s$)	I_{PP}	8	A
ESD according to IEC61000-4-2 air discharge	V_{ESD}	± 30	kV
ESD according to IEC61000-4-2 contact discharge		± 30	
Junction temperature	T_J	125	$^{\circ}C$
Storage temperature	T_{STG}	-55~150	$^{\circ}C$

■Electrical Characteristics ($T_a=25^{\circ}C$ Unless otherwise specified)

PARAMETER	Symbol	UNIT	Conditions	Min	Typ	Max
Reverse maximum working voltage	V_{RWM}	V				3.3
Reverse leakage current	I_R	nA	$V_{RWM} = 5V$			200
Reverse trigger voltage	V_{TRIG}	V	$I_{TRIG} = 2\mu A$	3.8		
Reverse holding voltage	V_{BR}	V	$I_{HOLD} = 50mA$	3.5		
Clamping voltage ¹⁾	V_{CL}	V	$I_{PP} = 1A, t_p = 8/20\mu s$			6
		V	$I_{PP} = 8A, t_p = 8/20\mu s$			10
Junction capacitance	C_J	pF	$V_R = 0V, f = 1MHz$			25

Notes:

(1). Non-repetitive current pulse, according to IEC61000-4-5.

■Ordering Information (Example)

PREFERED P/N	PACKING CODE	UNIT WEIGHT(mg)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
ESD3V3LBS	F1	Approximate 0.9	10000	100000	400000	7" reel



■ Characteristics (Typical)

Fig.1 8/20 μ s waveform per IEC61000-4-5

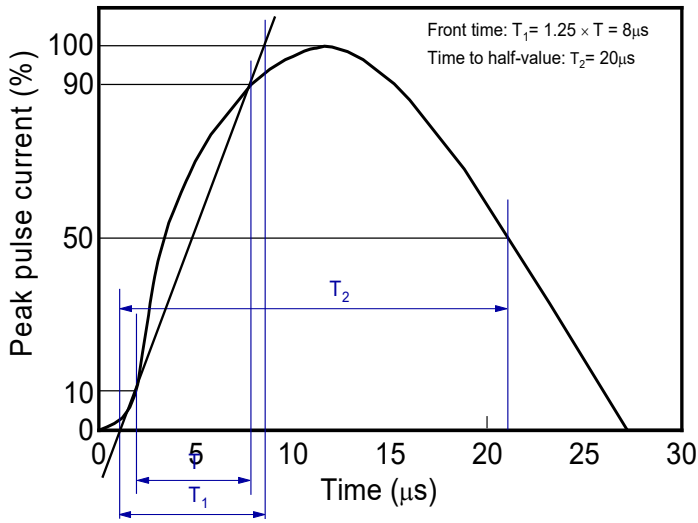


Fig.2 Contact discharge current waveform per IEC61000-4-2

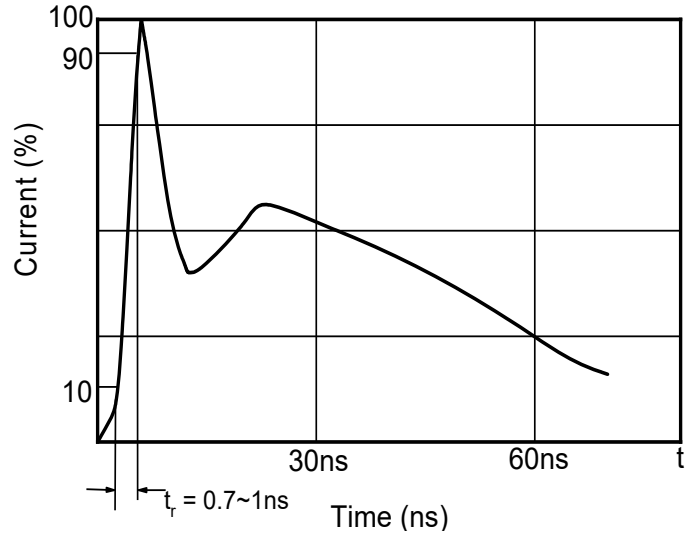


Fig.3 Clamping voltage vs. Peak pulse current

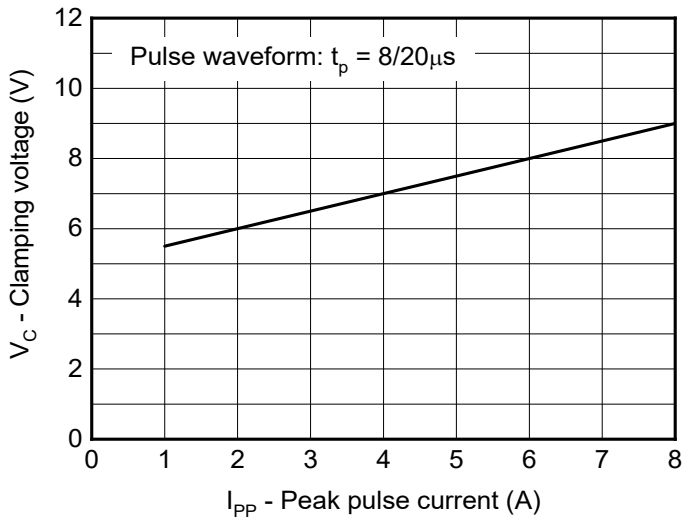


Fig.4 Capacitance vs. Reverse voltage

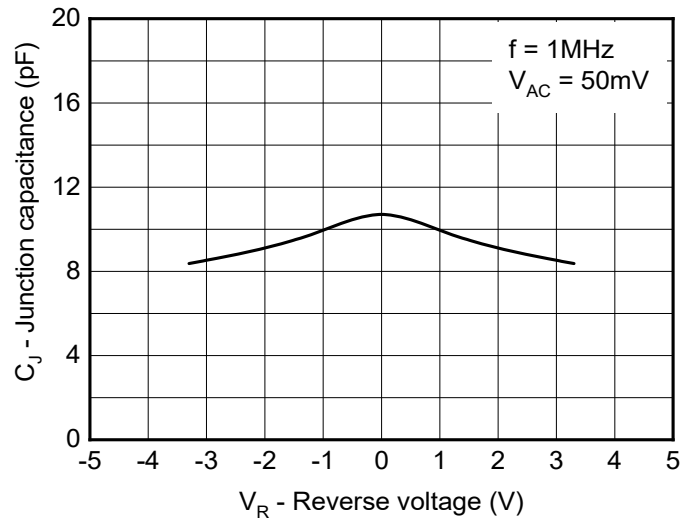


Fig.5 Non-repetitive peak pulse power vs. Pulse time

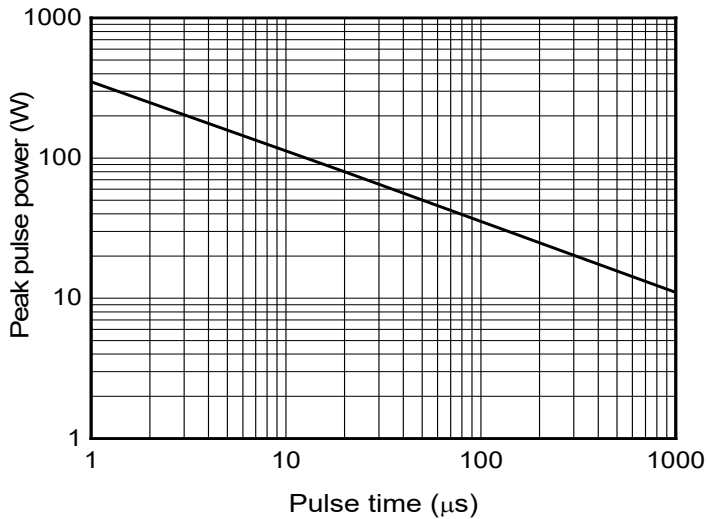
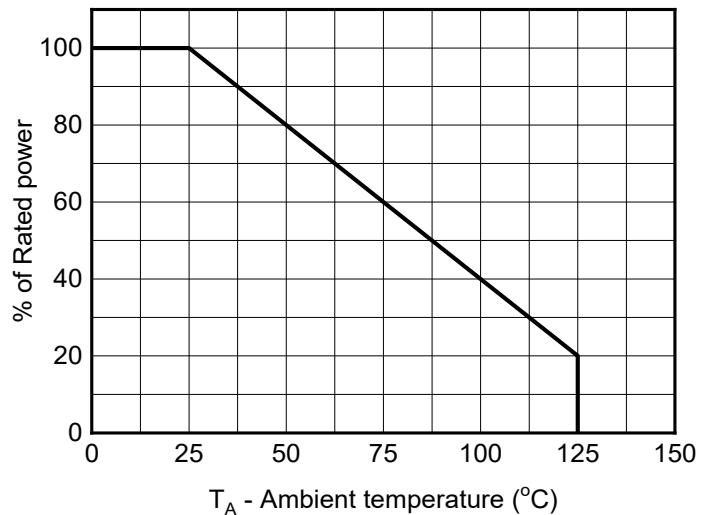


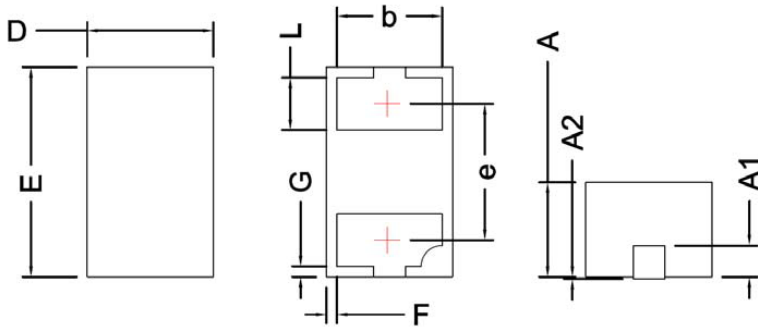
Fig.6 Power derating vs. Ambient temperature





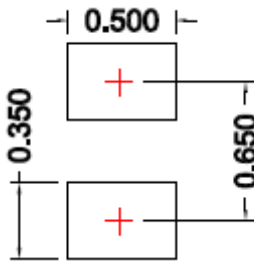
ESD3V3LBS

■ Outline Dimensions



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
D	0.50	0.60	0.70
E	0.90	1.00	1.10
A	0.45	0.50	0.55
A1	0.15 BSC		
A2			0.10
F	0.005		
G	0.005		
L	0.15	0.25	0.35
b	0.41	0.50	0.59
e	0.65 BSC		

■ Recommended PCB Layout



Unit:mm

Notes:

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met



ESD3V3LBS

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